

are transported from the tip to the substrate. Although the experiments performed on Au(111)/mica provide important information about the chemical identity of the transported species in these experiments, Au(111)/mica is a poor substrate for DPN. The deep valleys around the small Au(111) facets make it difficult to draw long (micrometer) contiguous lines with nanometer widths.

Although the nonannealed Au substrates are relatively rough (the root mean square roughness is 2 nm), we could deposit 30-nm lines with DPN; this distance is the average Au grain diameter of our thin film substrates and represents the resolution limit of DPN on this type of substrate (Fig. 2C). The 30-nm molecule-based line prepared on this type of substrate is discontinuous and follows the grain edges of the Au. Smoother and more contiguous lines can be drawn by increasing the line width to 100 nm (Fig. 2D) or presumably by using a smoother Au substrate. The width of the line depends on tip scan speed and the rate of transport of the alkanethiol from the tip to the substrate (relative humidity can change the transport rate). Faster scan speeds and a smaller number of traces give narrower lines.

We also used DPN to prepare molecular dot features to demonstrate the diffusion properties of the "ink" (Fig. 3, A and B). The ODT-coated tip was brought into contact (set point = 1 nN) with the Au substrate for a set period of time. For example, ODT dots 0.66 μm , 0.88 μm , and 1.6 μm in diameter were generated by holding the tip in contact with the surface for 2, 4, and 16 min, respectively (Fig. 3A, left to right). The uniform appearance of the dots probably reflects an even flow of ODT in all directions from the tip to the surface. Opposite contrast images were obtained by depositing dots of an alkanethiol derivative, 16-mercaptohexadecanoic acid, in an analogous fashion (Fig. 3B). This not only provides additional evidence that the molecules are being transported from the tip to the surface but also demonstrates the molecular generality of DPN.

We could generate arrays and grids in addition to individual lines and dots. An array of 25 ODT dots 0.46 μm in diameter, spaced 0.54 μm apart (Fig. 3C), was generated by holding an ODT-coated tip in contact with the surface (1 nN) for 20 s at 45% relative humidity without lateral movement to form each dot. A grid consisting of eight intersecting lines 2 μm in length and 100 nm wide (Fig. 3D) was generated by sweeping the ODT-coated tip on a Au surface at a 4- $\mu\text{m/s}$ scan speed with a 1-nN force for 1.5 min to form each line.

The resolution of DPN depends on several parameters, and its ultimate resolution is not yet clear. First, the grain size of the substrate affects DPN resolution much as the texture of paper controls the resolution of conventional writing. Second, chemisorption and self assembly can be used to limit the diffusion of the molecules

after deposition. The ODT patterns are stable whereas water forms metastable patterns (23). Third, the tip-substrate contact time and thus the scan speed influence DPN resolution. Fourth, relative humidity seems to affect the resolution of the lithographic process by controlling the rate of ODT transport from the tip to the substrate. The size of the water meniscus that bridges the tip and substrate depends on relative humidity (23). For example, the 30-nm-wide line (Fig. 1C) required 5 min to generate in a 34% relative humidity environment, whereas the 100-nm line (Fig. 1D) required 1.5 min to generate in a 42% relative humidity environment.

DPN is a simple but powerful method for transporting molecules from AFM tips to substrates at resolutions comparable to those achieved with much more expensive and sophisticated competitive lithographic methods, such as electron-beam lithography. It should be especially useful for the detailed functionalization of nanoscale devices prepared by more conventional lithographic methods (30, 31).

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Visible Quantum Cutting in $\text{LiGdF}_4\text{:Eu}^{3+}$ Through Downconversion

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For mercury-free fluorescent lamps and plasma display panels, alternative luminescent materials are required for the efficient conversion of vacuum ultraviolet radiation to visible light. Quantum cutting involving the emission of two visible photons for each vacuum ultraviolet photon absorbed is demonstrated in Eu^{3+} -doped LiGdF_4 with the concept of downconversion. Upon excitation of Gd^{3+} with a high-energy photon, two visible photons can be emitted by Eu^{3+} through an efficient two-step energy transfer from Gd^{3+} to Eu^{3+} , with a quantum efficiency that approaches 200 percent.

Luminescent materials with lanthanides are found in fluorescent tubes, color televisions, x-ray photography, lasers, infrared (IR) to visible light upconversion materials, and fiber amplifiers (1–3). Such applications rely

on the luminescence properties of lanthanide ions (sharp lines and high efficiency). In fluorescent lamps, phosphors on the inside wall of the glass tube convert the ultraviolet (UV) radiation (mainly with a wavelength λ of 254

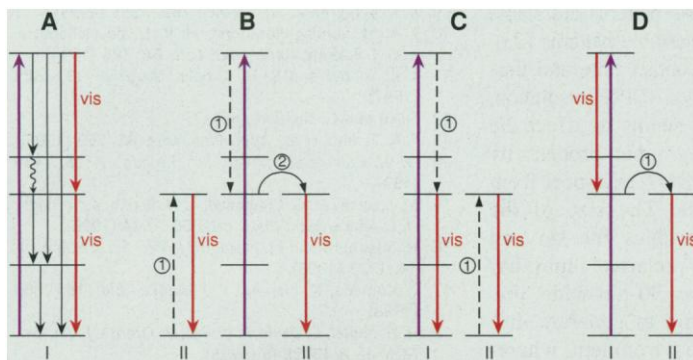
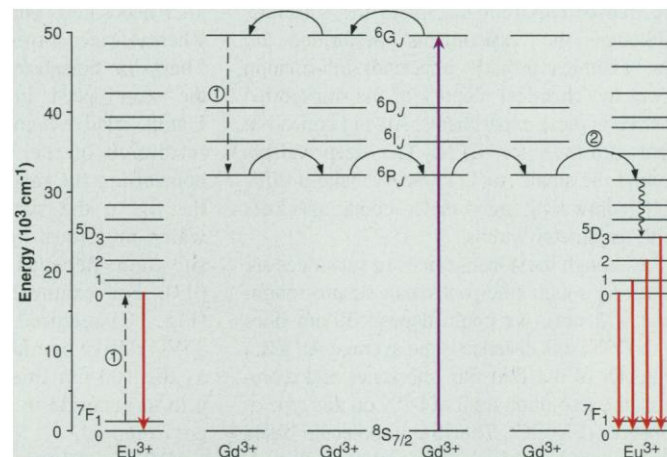


Fig. 1 (left). Energy level diagrams for two (hypothetical) types of lanthanide ions (I and II), showing the concept of downconversion. Type I is an ion for which emission from a high energy level can occur. Type II is an ion to which energy transfer takes place. **(A)** Quantum cutting on a single ion I by the sequential emission of two visible photons. **(B)** The possibility of quantum cutting by a two-step energy transfer. In the first step (indicated by ①), a part of the excitation energy is transferred from ion I to ion II by cross-relaxation. Ion II returns to the ground state by emitting one photon of visible light. Ion I is still in an excited state and can transfer the remaining energy to a second ion of type II (indicated by ②), which also emits a photon



in the visible spectral region, giving a quantum efficiency of 200%. **(C and D)** The remaining two possibilities involve only one energy transfer step from ion I to ion II. This is sufficient to obtain visible quantum cutting if one of the two visible photons can be emitted by ion I. **Fig. 2 (right)**. Energy level diagram of the $\text{Gd}^{3+}\text{-Eu}^{3+}$ system, showing the possibility of visible quantum cutting by a two-step energy transfer from Gd^{3+} to Eu^{3+} .

nm) that is generated in the Hg discharge to blue, green, and red light, yielding white light. The quantum efficiency of the lanthanide-based lamp phosphors is high ($\sim 90\%$) (*I*): For every 100 UV photons that are absorbed, 90 photons in the visible spectral region are emitted.

A challenge in the field of luminescence of lanthanide ions is the research in the vacuum ultraviolet (VUV) ($\lambda < 200$ nm) spectral region. Recently, this field has become important because of the need for phosphors for VUV excitation (1, 3–5). For example, Hg-free fluorescent lamps can be made by replacing Hg with a noble gas, such as Xe, as the discharge medium. A Xe discharge offers the advantage of immediate start-up: There is no delay in the emission of light (as is the case in conventional fluorescent lamps, where Hg must first evaporate). Immediate start-up is important in special applications (for example, for lamps in facsimile and copying machines and for car brake lights). In plasma display panels, a Xe discharge is also used to generate VUV radiation. In each pixel, the VUV radiation is converted to blue, green, or red light by a phosphor (4). For the conversion of the VUV radiation of a Xe discharge ($\lambda \approx 172$ nm) to visible light, alternative phosphors are needed. Three aspects are important in the development of new VUV phosphors: a higher efficiency, a higher stability, and a higher VUV absorption (5).

Although the generation efficiency of VUV radiation is high in a Xe discharge (higher than in other noble gas discharges), the light output (in lumens per watt) of Xe-

discharge lamps is lower than that of Hg-based fluorescent lamps. An important limitation in obtaining high energy efficiencies is inherent to the conversion of one VUV photon ($\lambda \approx 172$ nm) to one visible photon ($\lambda = 400$ to 700 nm). Even if the quantum efficiency of a phosphor is 100%, in this process, $\sim 65\%$ of the energy from the VUV photon is lost by nonradiative relaxation processes. For a Hg discharge ($\lambda = 254$ nm), the losses are lower ($\sim 50\%$). To reduce the higher energy losses, a quantum efficiency of more than 100% is required for phosphors in Xe-discharge fluorescent lamps. In theory, this is possible as the high energy of VUV photons that are generated in a noble gas discharge allows the emission of two photons in the visible spectral region per each VUV photon absorbed. This phenomenon has been studied for single lanthanide ions like Pr^{3+} and Tm^{3+} (6, 7), but for Tm^{3+} , a substantial amount of light is lost in the IR or UV spectral region.

whereas for Pr^{3+} , the main emission occurs in the deep violet region (~ 405 nm), where eye sensitivity is very low.

An alternative concept for obtaining quantum efficiencies of more than 100% is based on a combination of two lanthanide ions. Through partial energy transfer between the ions, a high quantum efficiency (close to 200%) can be obtained. This process is the opposite of the process that is known as "Addition de Photons par Transfert d'Energie" (APTE) [which was discovered by Auzel in 1966 (8)] and also known as upconversion (1, 2). Because of this analogy, we call the quantum cutting through energy transfer "downconversion." The concept is illustrated (Fig. 1) with two types of ions, I and II, with hypothetical energy level schemes. Efficient visible quantum cutting by a two-photon emission from a high energy level for a single lanthanide ion is theoretically possible (Fig. 1A, red lines). However,

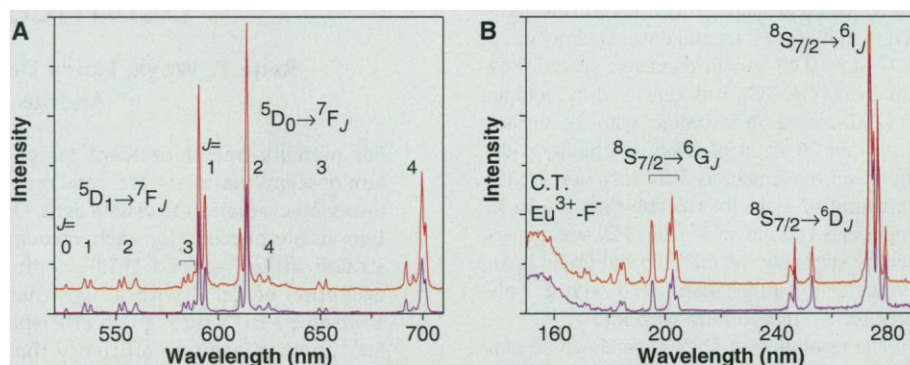


Fig. 3. (A) Emission spectra of $\text{LiGdF}_4:\text{Eu}^{3+}$ (0.5 mol%) upon excitation in the 6I_J levels of Gd^{3+} at 273 nm (violet line) and upon excitation in the 6G_J levels of Gd^{3+} at 202 nm (red line), both at 300 K. The spectra are scaled on the $^5D_1 \rightarrow ^7F_J$ emission intensity. **(B)** Excitation spectra of $\text{LiGdF}_4:\text{Eu}^{3+}$ (0.5 mol%) monitoring the $^5D_1 \rightarrow ^7F_2$ emission of Eu^{3+} at 554 nm (violet line) and the $^5D_0 \rightarrow ^7F_2$ emission at 614 nm (red line), both at 300 K. The spectra are scaled on the $^8S_{7/2} \rightarrow ^6I_J$ excitation intensity.

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competing emissions in the IR and UV regions (Fig. 1A, black lines) can also occur. Possibilities for visible quantum cutting involving the known energy levels of lanthanides (up to 50,000 cm⁻¹) have been studied with the Judd-Ofelt theory, but efficient visible quantum cutting by the sequential emission of two visible photons on one lanthanide ion has not been found (3, 7). The use of a second type of lanthanide ion, to which a part of the excitation energy can be transferred and which subsequently emits a visible photon, can prevent losses in the IR and UV regions. There are three possibilities for visible quantum cutting through energy transfer (Fig. 1, B through D), all of which have a theoretical quantum efficiency of 200%.

The emission of two visible photons per each absorbed VUV photon is possible with the Gd³⁺-Eu³⁺ couple (Fig. 2). We have observed visible emission from Gd³⁺ at ~590 nm upon excitation in the ⁶G_J levels at ~50,000 cm⁻¹ (9); *J* is the total angular momentum quantum number. The emission could be assigned to the ⁶G_J → ⁶P_{7/2} transition. The energy of this emission matches the ⁷F_J → ⁵D₀ excitation energy on Eu³⁺. Visible quantum cutting of the type indicated in Fig. 1B can now occur. Upon excitation in the ⁶G_J levels of Gd³⁺, energy is transferred in the first step by cross-relaxation between Gd³⁺ in the ⁶G_J state and Eu³⁺ in the ⁷F_J state, resulting in Gd³⁺ in the ⁶P_J state and Eu³⁺ in the ⁵D₀ state. In the second step, the Gd³⁺ ion in the ⁶P_J state transfers the remaining excitation energy to a high excited state of a second Eu³⁺ ion. Fast relaxation from this high excited state to the ⁵D_J states occurs. Both steps result in the emission of a visible photon due to ⁵D_J → ⁷F_J transitions on Eu³⁺, where the energy transfer from Gd³⁺ to Eu³⁺ is mediated by energy migration over the excited states of the Gd³⁺ ions. Energy migration over the Gd sublattice in concentrated Gd compounds is well known and allows an efficient energy transfer with low Eu concentrations, because the Eu³⁺ ions act as traps for the excitation energy migrating over the Gd sublattice (1, 2).

To investigate if and with what efficiency the visible quantum cutting in the Gd³⁺-Eu³⁺ system occurs, we synthesized polycrystalline powder samples of LiGdF₄:Eu³⁺ [0.5 mole percent (mol%)] (9). Extreme care was taken to prevent contamination of the samples with oxygen. The luminescence measurements were performed on set-ups, which are described in detail in (9). In determining the efficiency of the quantum cutting process, it may seem straightforward to measure the quantum efficiency of the phosphor under VUV excitation. This method has two drawbacks. First, it is difficult to determine the quantum efficiency of a weakly absorbing phosphor. Because the excitation transitions on the Gd³⁺ ion are parity-forbidden transitions within the 4f⁷ configuration, the

VUV absorption is weak, and the error in the determination of the fraction of the VUV radiation that is absorbed is large. This gives a large error in the quantum efficiency calculated. The second problem is related to other processes that can influence the quantum efficiency, especially in a phosphor that has not been optimized. Nonradiative losses at defects and impurities can lower the quantum efficiency, and even if the two-step energy transfer process occurs with high efficiency, a quantum efficiency that is much lower than 200% is measured. An optimized phosphor could still have a quantum efficiency close to 200%.

It is possible to determine the efficiency of the two-step energy transfer process (emitting two photons in the visible spectral region) relative to the process that emits only one visible photon (direct energy transfer from the ⁶G_J level of Gd³⁺ to a Eu³⁺ level at ~50,000 cm⁻¹). In the emission spectra, the intensity distribution over the different Eu³⁺ emission lines depends on the energy transfer process. The percentage of the Gd³⁺ ions that relax through a two-step energy transfer to Eu³⁺ can be determined from changes in the ratio of the intensity of the ⁵D₀ emission and the other ⁵D_J emissions for different excitation wavelengths. The emission spectrum (Fig. 3A, violet line) shows that the emission lines corresponding to transitions from the ⁵D₀ level are the strongest, but emission from the ⁵D₁ levels was also observed. Weak emission lines from the ⁵D₂ and the ⁵D₃ levels were observed but not shown (10). The emission spectrum is in good agreement with spectra for Eu³⁺ in LiYF₄ and LiGdF₄ (11). The ratio of the intensities of the ⁵D₀, ⁵D₁, ⁵D₂, and ⁵D₃ emission lines (the branching ratio) is the same for excitation in a high Eu³⁺ level (above the ⁵D₃ level) or after direct energy transfer from Gd³⁺ to Eu³⁺. This branching ratio, determined by competition between multiphonon relaxation and radiative decay from the ⁵D_J levels, is called the "normal" branching ratio.

Upon excitation in the ⁶G_J level, quantum cutting through a two-step energy transfer can occur. In the first step of this process, only the ⁵D₀ level of Eu³⁺ is excited (Fig. 2). In the second step, energy is transferred from the ⁶P level of Gd³⁺ to a high energy level of Eu³⁺. This second step yields the normal branching ratio for the different ⁵D_J emission lines. As the first energy transfer step only gives the emission from the ⁵D₀ level of Eu³⁺, a substantial increase of the relative intensity of the ⁵D₀ emission intensity upon excitation in the ⁶G_J levels is expected, if quantum cutting through a two-step energy transfer occurs as indicated in Fig. 2. A comparison of the emission spectra for excitation in the ⁶I_J levels of Gd³⁺ (273 nm) (Fig. 3A, violet line) and in the ⁶G_J levels of Gd³⁺ (202 nm) (Fig. 3A, red line) shows that the relative intensity of the ⁵D₀ emission lines is indeed more than a factor of 2 stronger for

excitation in the ⁶G_J levels than for excitation in the ⁶I_J levels. The ⁵D₀/⁵D_{1,2,3} emission intensity ratio is 3.4 for excitation in the ⁶I_J levels (this is the normal branching ratio). Upon excitation in the ⁶G_J levels of Gd³⁺ (or in other Gd³⁺ levels in the VUV), the ⁵D₀/⁵D_{1,2,3} emission intensity ratio is 7.4. From these intensity ratios, the efficiency of the cross-relaxation step can be determined with

$$\frac{P_{CR}}{P_{CR} + P_{DT}} = \frac{R(^5D_0/^5D_{1,2,3})_{G_J} - R(^5D_0/^5D_{1,2,3})_{I_J}}{R(^5D_0/^5D_{1,2,3})_{I_J} + 1}$$

Here, P_{CR} is the probability for cross-relaxation, and P_{DT} is the probability for the direct energy transfer from Gd³⁺ to Eu³⁺. $R(^5D_0/^5D_{1,2,3})$ is the ratio of the ⁵D₀ and the ⁵D_{1,2,3} emission intensities. The subscript (⁶G_J or ⁶I_J) indicates the excitation level for which the ratio is obtained. From the $R(^5D_0/^5D_{1,2,3})$ values of 3.4 (for ⁶I_J excitation) and 7.4 (for ⁶G_J excitation), the ratio $P_{CR}/(P_{CR} + P_{DT})$ was calculated to be ~0.9, showing that 9 of 10 Gd³⁺ ions in the ⁶G_J excited state relax through a two-step energy transfer to Eu³⁺, yielding two visible photons. One of 10 Gd³⁺ ions in the excited ⁶G_J state transfers all its energy directly to a high energy level of Eu³⁺, resulting in the emission of only one visible photon. In this way, a visible quantum efficiency of 190% can be obtained if nonradiative losses (for example, losses due to energy migration and energy transfer to nonradiative quenching centers in the lattice) can be prevented. Experience with lanthanide phosphors has shown that nonradiative losses can be low if the synthesis procedure is optimized. Thus, in an optimized LiGdF₄:Eu³⁺ phosphor, a quantum efficiency close to 200% may be possible. Losses due to UV emission from Gd³⁺ are negligible; in the emission spectra, only very weak Gd³⁺ emission lines were observed. The intensity of these lines was much less than 1% of the total emission intensity, which shows that the energy transfer from Gd³⁺ to Eu³⁺ through energy migration is efficient.

In the excitation spectra of two Eu³⁺ emission lines, the relative intensity of Gd³⁺ excitation lines corresponding to transitions in the VUV is more than a factor of 2 higher in the excitation spectrum of the ⁵D₀ emission (Fig. 3B, red line) than in the excitation spectrum of the ⁵D₁ emission (Fig. 3B, violet line). This is in agreement with the observations in the emission spectrum presented above, and it confirms the presence of quantum cutting through down-conversion. The demonstration of down-conversion in LiGdF₄:Eu³⁺ with a quantum efficiency close to 200% in the orange or red spectral region is an important step in

the development of more efficient Hg-free fluorescent tubes and plasma display panels and has triggered the search for downconversion phosphors with quantum efficiencies that are higher than 100% in the blue and green spectral regions.

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Argon-Lead Isotopic Correlation in Mid-Atlantic Ridge Basalts

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Step-heating analyses for Mid-Atlantic Ridge glass samples show that maximum $^{40}\text{Ar}/^{36}\text{Ar}$ values correlate with $^{206,207,208}\text{Pb}/^{204}\text{Pb}$. These correlations hold for the whole Atlantic Ocean and therefore are unlikely to result from shallow-level contamination processes. Instead, they are taken as mixing hyperbolae between the degassed-depleted upper mantle and a recycled component characterized by high $^{206}\text{Pb}/^{204}\text{Pb}$ ratios (19 to 21) and low $^{40}\text{Ar}/^{36}\text{Ar}$ ratios (300 to 1000). These relations imply that argon may also be a tracer of mantle recycling.

Rare gas isotopes have been successfully used to constrain the timing of atmosphere generation by mantle degassing (1–5), but, except for helium (6, 7), they have been less useful as tracers of mantle heterogeneities, largely because of contamination by atmospheric rare gases (8, 9). Measuring the isotopic composition of mantle rare gases trapped in mid-ocean ridge basalt (MORB) has always met the difficulty of separating the magmatic gas from a widespread atmospheric component, a particular problem for argon. Addition of atmospheric Ar was long considered to occur during eruption on the sea floor. Indeed, the slowly cooled inner parts of submarine lava flows generally appear more contaminated than the outer layers, quenched to glass (8, 9). In step-heating degassing on glass samples, argon with $^{40}\text{Ar}/^{36}\text{Ar}$ ratios of 300 to 5000 is often

released in the low-temperature steps (500° to 700°C). This gas is confirmation that weakly bound atmospheric argon is present in many samples (9–13).

In higher temperature steps, argon with high to very high $^{40}\text{Ar}/^{36}\text{Ar}$ ratios of 10,000 to 30,000 is commonly released (9–13). For a given sample, the maximum value obtained in a series of temperature steps is taken as the most representative of the true magmatic value, at least a minimum value because some contaminant argon may still be present. Such high $^{40}\text{Ar}/^{36}\text{Ar}$ ratios, and similar isotopic anomalies for the other rare gases, record the highly degassed character of the upper mantle (4, 5, 9, 11), or at least of parts of it.

Overall, $^{40}\text{Ar}/^{36}\text{Ar}$ maxima from step-heating analyses obtained for numerous mid-ocean ridge glass samples from diverse locations worldwide display a large range of values, from 500 to about 30,000 (3, 9, 12–16). Most authors have assumed that this variability reflects the inability of the analysis techniques to separate completely magmatic argon from contaminant argon (9, 12, 14–16). If this were the case, upper-mantle argon could be isotopically uniform and have a high $^{40}\text{Ar}/^{36}\text{Ar}$ signature. However, neither step-heating nor step-crushing of glass samples have ever demonstrated the existence of this single mantle argon component. In contrast, decades of improving analyses have shown that the variability of $^{40}\text{Ar}/^{36}\text{Ar}$ maxima from step-heating or crushing is the rule. Therefore, there is a possibility that

this variability may be not merely due to contamination, but is at least partly inherent to mantle argon. Argon might then bear the record of some mantle heterogeneities, in the same way as Sr, Nd, or Pb.

To test this possibility, we analyzed the IGP rare gas laboratory's large argon isotopic database for MORB to determine whether any correlation could be found between $^{40}\text{Ar}/^{36}\text{Ar}$ ratios and Pb isotope data from the literature. Initially, we used only step-heating data where more than one temperature step was performed. Samples with a $^4\text{He}/^3\text{He}$ ratio lower than 75,000 ($^3\text{He}/^4\text{He}$ higher than 9.5 Ra) were not used, as they are considered to be influenced by primitive plumes from the lower mantle. For every sample, the highest $^{40}\text{Ar}/^{36}\text{Ar}$ value from the different temperature steps was retained. When replicate argon analyses were performed, only the highest value was selected. A few samples with $^{40}\text{Ar}/^{36}\text{Ar}$ ratios lower than 1000 were discarded as possibly severely contaminated. Then, one maximum $^{40}\text{Ar}/^{36}\text{Ar}$ ratio from step-crushing was added (and one datum from total fusion). In all, 20 analyses were identified for North and South Atlantic Ocean samples having the same identification in our database for Ar and in the literature for Pb. We also included recent data for the Azores section of the Mid-Atlantic Ridge, with radiogenic lead and $^{40}\text{Ar}/^{36}\text{Ar}$ mostly lower than 1000, giving 28 samples (17).

The $^{40}\text{Ar}/^{36}\text{Ar}$ ratio in these samples correlates with $^{206}\text{Pb}/^{204}\text{Pb}$, $^{207}\text{Pb}/^{204}\text{Pb}$, and $^{208}\text{Pb}/^{204}\text{Pb}$ ratios. Samples with high $^{40}\text{Ar}/^{36}\text{Ar}$ ratios have typical depleted-mantle $^{206}\text{Pb}/^{204}\text{Pb}$ ratios; those with low $^{40}\text{Ar}/^{36}\text{Ar}$ have radiogenic lead (Fig. 1). The curvature of these Ar-Pb isotopic correlations is weak.

These correlations cannot reasonably be attributed, directly or indirectly, to shallow-level contamination by atmospheric argon; this would mean that the samples most contaminated in argon are the most radiogenic in Pb, for which there is no obvious reason. In the case of mixing between two magmas, it is unlikely that the magma with the most radiogenic lead would also be the most degassed (hence the most susceptible to contamination), especially over a span of 20,000 km

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